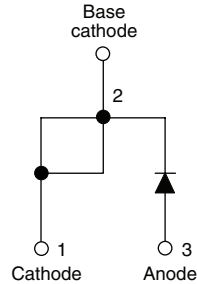


## Input Rectifier Diode, 40 A



TO-247AC modified



### DESCRIPTION/FEATURES

The 40EPS..PbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.



**RoHS\***  
COMPLIANT

Typical applications are in input rectification and these products are designed to be used with Vishay HPP Switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level and lead (Pb)-free.

### PRODUCT SUMMARY

$V_F$ at 40 A	1.1 V
$I_{FSM}$	475 A
$V_{RRM}$	800/1200 V

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	40	A
$V_{RRM}$	Range	800/1200	V
$I_{FSM}$		475	A
$V_F$	40 A, $T_J = 25\text{ °C}$	1.1	V
$T_J$		- 40 to 150	°C

### VOLTAGE RATINGS

PART NUMBER	$V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ AT 150 °C mA
40EPS08PbF	800	900	1
40EPS12PbF	1200	1300	

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 105\text{ °C}$ , 180° conduction half sine wave	40	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	10 ms sine pulse, rated $V_{RRM}$ applied	400	
		10 ms sine pulse, no voltage reapplied	475	
Maximum $I^2t$ for fusing	$I^2t$	10 ms sine pulse, rated $V_{RRM}$ applied	800	A <sup>2</sup> s
		10 ms sine pulse, no voltage reapplied	1131	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	11 310	A <sup>2</sup> √s

\* Pb containing terminations are not RoHS compliant, exemptions may apply

# 40EPS..PbF High Voltage Series



Vishay High Power Products Input Rectifier Diode, 40 A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	20 A, $T_J = 25\text{ }^\circ\text{C}$		1.0	V
		40 A, $T_J = 25\text{ }^\circ\text{C}$		1.1	
Forward slope resistance	$r_t$	$T_J = 150\text{ }^\circ\text{C}$		7.16	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$			0.74	V
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_{RRM}$	0.1	mA
		$T_J = 150\text{ }^\circ\text{C}$		1.0	

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$			- 40 to 150	$^\circ\text{C}$
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation		0.6	$^\circ\text{C}/\text{W}$
Maximum thermal resistance, junction to ambient	$R_{thJA}$			40	
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, flat, smooth and greased		0.2	
Approximate weight				6	g
				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style TO-247AC modified (JEDEC)		40EPS08	
				40EPS12	



# 40EPS..PbF High Voltage Series

Input Rectifier Diode, 40 A Vishay High Power Products

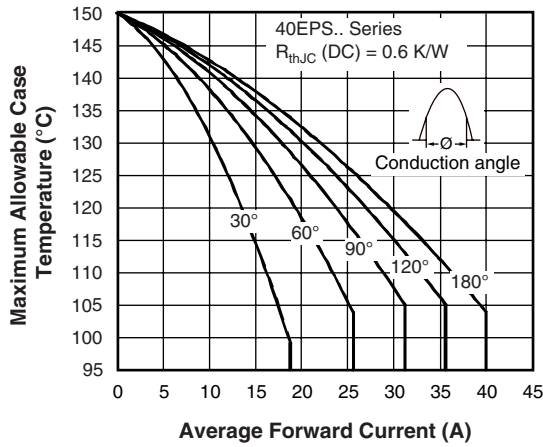


Fig. 1 - Current Rating Characteristics

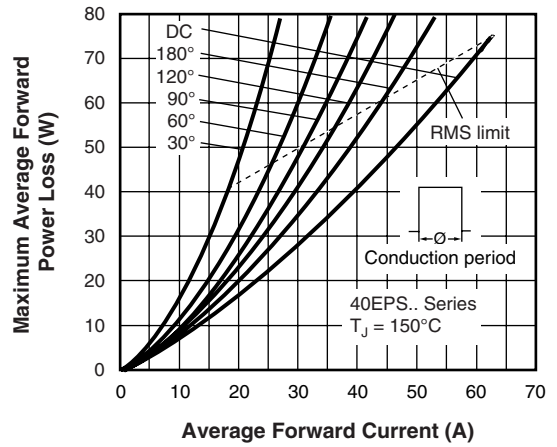


Fig. 4 - Forward Power Loss Characteristics

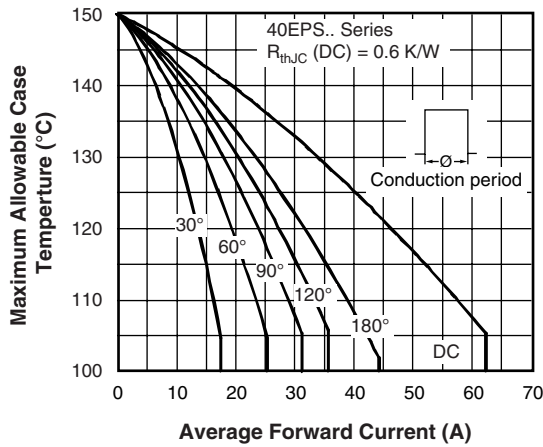


Fig. 2 - Current Rating Characteristics

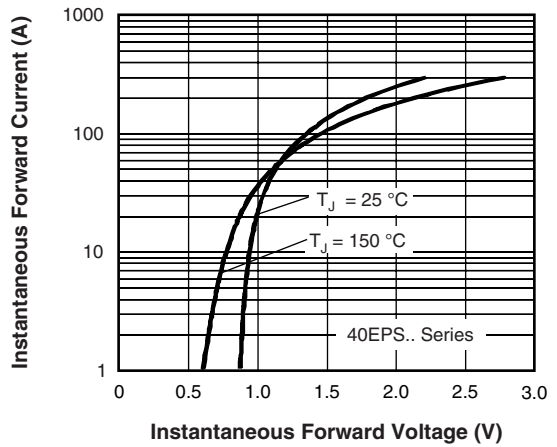


Fig. 5 - Forward Voltage Drop Characteristics

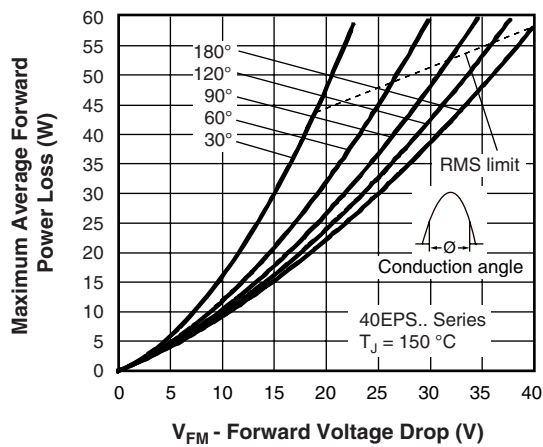


Fig. 3 - Forward Power Loss Characteristics

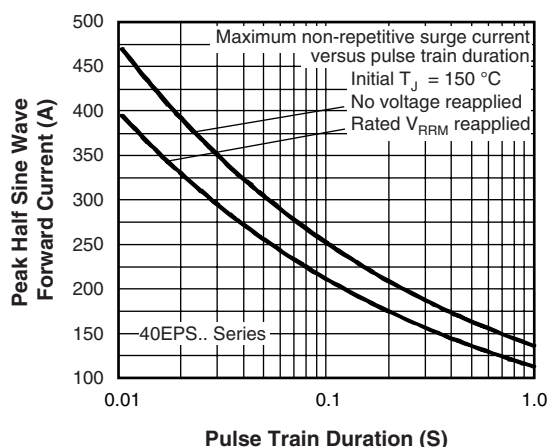


Fig. 6 - Maximum Non-Repetitive Surge Current

# 40EPS..PbF High Voltage Series

Vishay High Power Products Input Rectifier Diode, 40 A

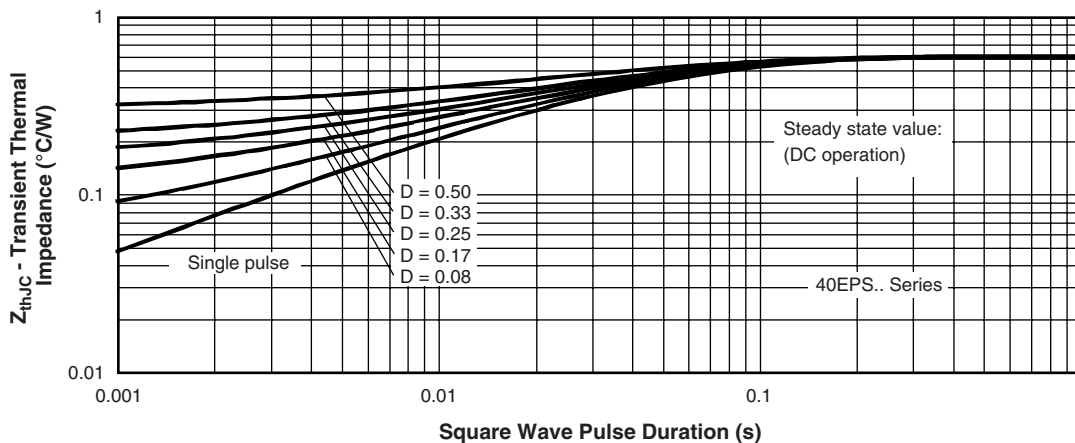


Fig. 7 - Thermal Impedance  $Z_{thJC}$  Characteristics

## ORDERING INFORMATION TABLE

Device code	<b>40</b>	<b>E</b>	<b>P</b>	<b>S</b>	<b>12</b>	<b>PbF</b>
	①	②	③	④	⑤	⑥
	<b>1</b>	-	Current rating (40 = 40 A)			
	<b>2</b>	-	Circuit configuration: E = Single diode			
	<b>3</b>	-	Package: P = TO-247AC modified			
	<b>4</b>	-	Type of silicon: S = Standard recovery rectifier			
	<b>5</b>	-	Voltage rating		08 = 800 V	
	<b>6</b>	-	• None = Standard production • PbF = Lead (Pb)-free		12 = 1200 V	

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95253">http://www.vishay.com/doc?95253</a>
Part marking information	<a href="http://www.vishay.com/doc?95255">http://www.vishay.com/doc?95255</a>



## Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.